# Competition between crystalline electric eld singlet and itinerant states of felectrons

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### A bstract

A new kind of phase transition is proposed for lattice ferm ion systems with simpli ed  $f^2$  con gurations at each site. The free energy of the model is computed in the mean-eld approximation for both the itinerant state with the K ondo screening, and a localized state with the crystalline electric eld (CEF) singlet at each site. The presence of a rst-order phase transition is demonstrated in which the itinerant state changes into the localized state toward lower temperatures. In the half-led case, the insulating state at high temperatures changes into a metallic state, in marked contrast with the M ott transition in the H ubbard model. For comparison, corresponding states are discussed for the two-in purity K ondo system with  $f^1$  conguration at each site.

# 1 Introduction

In some uranium compounds with  $5f^2$  con guration ( $U^{4+}$ ) the CEF ground-state can be a nonm agnetic singlet. The CEF singlet is also realized in some praseodymium compounds with  $4f^2$  con guration ( $Pr^{3+}$ ). In these cases the spin entropy of the system can go to zero as temperature decreases even though interactions with conduction electrons or with f electrons at other sites are absent. This is in striking contrast with the case of cerium compounds with  $4f^1$  con guration ( $Ce^{3+}$ ); the entropy does not disappear at zero temperature if a Ce ion is isolated because of the K ram ers degeneracy associated with the  $f^1$  con guration. As a result the system chooses, depending on the interaction between Ce sites, am ong a m agnetically ordered state, a Ferm i liquid state, a superconducting state, and so on in which the entropy vanishes at zero temperature.

In these lattice ferm ion systems, which we call the  $f^2$  lattice hereafter, the itinerant state is also possible if the hybridization is large enough. Thus both the localized felectron picture and the band picture can be a starting point to understand the actual compounds with  $f^2$  con guration. The most interesting situation occurs when the energy scale of the CEF singlet state is comparable to that of the itinerant state. Then both states compete for the stability.

Suppose we have the CEF singlet as the ground state of the  $f^2$  lattice, but its energy is only a little lower than the itinerant state. If the itinerant state is metallic, the entropy increases linearly as tem perature increases. The tem perature scale here is the K ondo tem perature, and is related to the large density of states at the Ferm i surface. On the other hand increase of the felectron part of the entropy in the CEF state follows the exponential law, and is much less signi cant in a low tem perature range. Thus there is a possibility for a phase transition to occur from the CEF singlet state to the itinerant state as tem perature increases in the  $f^2$  lattice system. Even if the itinerant state is a K ondo insulator, the entropy can increase m ore rapidly than that in the CEF state since the energy gap decreases with tem perature. In the latter case the system changes from a metal to an insulator as tem perature increases. This is opposite to the case of the M ott transition where the low-tem perature phase is an insulator.

The purpose of this paper is to demonstrate the presence of a phase transition between the CEF singlet and itinerant states in the  $f^2$  lattice system at zero and nite temperatures. As the rst step to explore

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an  $f^2$  lattice system, we take the simplest possible approach and apply the mean eld approximation with account of both it inerant and localized characters of felectrons. The plan of the paper is as follows: In the next section, we introduce the model and derive the mean- eld equations. The same approximation scheme is applied to the two-impurity K ondo system with f<sup>1</sup> conquration at each site in Section 3. It turns out helpful to com pare the electronic states of both models. The relative stability of di erent phases in both the f<sup>2</sup> lattice system and the two-impurity K ondo system is studied in Section 4. P resence of the phase transition at nite tem peratures is demonstrated. The nal section is devoted to discussion of results with attention to possible experim ental relevance.

#### 2 M odel and M ean-Field Equations

W e introduce an  $f^2$  lattice m odel as follow s:

$$H = \begin{pmatrix} X & X \\ & & \\ &$$

where i is the site index, and and are channels of conduction and felectrons, respectively. We express the CEF singlet and triplet using a pseudo-spin operator of f electrons for each channel:  $S_i^f$  =  $f_i^{\rm Y} \sim f_i$  , where  $\sim$  is the vector composed of Paulim atrices. The spin operator of conduction (1=2) electrons is given by  $S_i^c = (1=2)^p \quad c_i^y \sim c_i$ . In eq. (1), the second term with J > 0 gives antiferrom agnetic interaction between f and conduction electrons on each site. In the presence of the potential scattering term  $(1=4)n_i^f n_i^c$ , the K ondo scale  $T_K = D \exp(1=J_{c0})$  is reproduced correctly in the mean-eld approximation. Here, D is a half width of a conduction band and  $_{\rm c0}$  is the density of states per spin of conduction electrons at the Fermi level. We note that the sum of the spin exchange and potential scattering term s is half of the permutation operator whose eigenvalue is 1 for the quasi-spin triplet and is 1 for the singlet. The last term with I > 0 in eq. (1) represents the CEF splitting. This splitting I is also correctly given by the mean- eld approximation due to the term  $(1=4)r_{11}^{f_1}n_{12}^{f_2}$ . The restriction  $n_1^f = 1$  is imposed on eq. (1) to simulate the strong C oulom b repulsion between f electrons.

W e take a m ean eld as

$$V_i = \frac{J}{2} X h f_i^y c_i i$$
 (2)

for = 1;2 and = ; . This mean eld represents the ctitious hybridization between fand conduction electrons. We say " ctitious hybridization" in the sense that the real hybridization is absent in the model with xed occupation of f states. How ever we neglect in this paper the phase uctuation which makes the m ean eld vanish. The physical motivation for the neglect will be discussed in the nal section. A nother mean-eld is given by

$$R_{i} = \frac{I}{2}^{X} h f_{i1}^{y} f_{i2} i$$
(3)

which expresses the mixing between two forbitals on each site. This mixing gives rise to bondingantibonding splitting of localized levels. In eqs. (2) and (3) we assume that the mixing is allowed only for the same spin directions. The Lagrange multiplier term s

X X  
$$i (n_{i}^{f} 1)$$
  
 $i = 1;2$ 

are added to eq. (1) to enforce the constraints on the num ber of felectrons. In the mean- eld approxim ation the number of felectron per site and channel is xed only as average. Therefore care is necessary

about spurious charge uctuations included. We discuss this aspect of the mean-eld theory again in the nal section of the paper.

A ssum ing equivalence of di erent sites and channels, we put  $"_k = "_k; V_i = V = j V j exp(i);$ R<sub>i</sub> = R and i = . Setting the origin of energy at the Fermilevel, we write the free energy per site as

$$F = \frac{T}{N_{s}} X X_{k;!_{n}} tr \ln \frac{M(k;i!_{n})}{T} + 2 J + \frac{I}{4} R_{f} + \frac{8}{J_{c0}} + \frac{2Rf}{I}; \qquad (4)$$

where  $N_s$  is the total number of the sites,  $\mathbf{u}_f = J + I = 4$  and  $= {}_{c0} \frac{1}{y} \frac{2}{f}$ . The 2 2 m atrix M with M atsubara frequency i! n has components

$$M = i!_{n} + u_{f} + \frac{2y j}{i!_{n}} (= 1;2);$$
 (5)

$$M_{12} = R + \frac{2y f}{1!_n "_k} ; \qquad (6)$$

$$M_{21} = R + \frac{2 y j}{i!_{n} y_{k}} ; \qquad (7)$$

where = fexp(i) + exp(i) g=2 with = 1 2 (=;). Here we represent the magnitude of the hybridization between di erent channels of felectrons via conduction electrons by the parameter

. Let us take the bases in which the on-site hybridization between f and conduction electrons occurs only with the same channel. Even for this case, the intersite hybridization between the channels 1 and 2 of felectrons can occur. This is because the point group symmetry around each site is not relevant to intersite interactions. From a detailed analysis we nd that R and can be chosen real. Then we can assume 1 1 in the following.

We derive the mean-eld equations by requiring the free energy to be stationary against variation of  $; \mathbf{u}_{\mathrm{f}}$  and R. As a result three characteristic states appear: First the K ondo state is the itinerant state where felectrons hybridize with conduction electrons ( $\mathbf{6}$  0, R = 0). Secondly the CEF state is the localized state where felectrons form the singlet of quasi-spins at each site (= 0, R  $\mathbf{6}$  0). Thirdly the mixed state has a character interpolating between the K ondo and CEF states ( $\mathbf{6}$  0, R  $\mathbf{6}$  0). For the CEF state we always have the solution  $= \mathbf{u}_{\mathrm{f}} = 0$  and R = Iff(R) f(R)g=2. Here, f(w) = 1=fexp(w=T) + 1g is the Ferm i distribution function with energy w.

In the following we consider the case where the number N<sub>c</sub> of conduction electrons is twice the number of lattice sites, and the conduction bands without hybridization have constant density of states  $_{c0} = 1 = (2D)$  between the band edges D. Then the system has the insulating ground state if felectrons form energy bands, since f and conduction electrons have the hybridization gap at the Ferm i level. This is called the K ondo insulator. If felectrons are localized, on the other hand, the Ferm i level lies in the middle of the conduction band, and the system becomes metallic. For the K ondo and mixed states, each conduction band is split into two pieces with a band gap between them. We use the notation  $E = R_{f} (1)^{p(\cdot)}R$ , and  $= 1 + (1)^{p(\cdot)}$  where p(a) = 1, p(b) = 0 with = a; b. The band edges after splitting are given by

$$D_{1} = \frac{D + E}{2} \frac{D + E}{2} \frac{1 + \frac{8}{c_{0}(D + E)^{2}}}{1 + \frac{8}{c_{0}(D + E)^{2}}};$$

$$D_{2} = \frac{D + E}{2} \frac{D - E}{2} \frac{1 + \frac{8}{c_{0}(D - E)^{2}}}{1 + \frac{8}{c_{0}(D - E)^{2}}};$$

$$D_{3} = \frac{D + E}{2} + \frac{D + E}{2} \frac{1 + \frac{8}{c_{0}(D + E)^{2}}}{1 + \frac{8}{c_{0}(D - E)^{2}}};$$

$$D_{4} = \frac{D + E}{2} + \frac{D - E}{2} \frac{1 + \frac{8}{c_{0}(D - E)^{2}}}{1 + \frac{8}{c_{0}(D - E)^{2}}};$$

Then the mean-eld equations are given by

$$Z_{D_{2b}} Z_{D_{4b}}$$

$$+ \frac{4}{(w - E_{b})^{2}} f(w) = 1 + \frac{2R}{I};$$
(8)

$$\sum_{D_{2a}} Z_{D_{4a}} + \frac{4}{(w - E_{a})^{2}} f(w) = 1 - \frac{2R}{I};$$
 (9)

$$\begin{array}{rcl} & & & Z_{D_{2b}} & Z_{D_{4b}} & \cdot \\ & & + & & & dw \frac{b}{w & E_b} f(w) \\ & & & & \\ D_{1b} & & D_{3b} & & \\ & & & Z_{D_{2a}} & Z_{D_{4a}} \\ + & & + & & & dw \frac{a}{w & E_a} f(w) = & \frac{2}{J_{c0}} \\ \end{array}$$
(10)

W e solve eqs.(8)-(10) for various values of dimensionless parameters  $I=T_K$  and at zero and nite temperatures. W e note that the mixed state is metallic because the condition R  $\frac{6}{6}$  0 requires a nite density of states between bonding and antibonding f levels.

# 3 Two-Impurity Kondo System

In the course of understanding the electronic state in the  $f^2$  lattice system, a necessary step is to clarify the di erence from the  $f^2$  in purity system. This is purity system is further related to the two-in purity K ondo system with  $f^1$  conguration at each site. Namely, the  $f^2$  is purity is considered as the shortdistance limit of two K ondo in purities. Fortunately we have detailed know ledge about the two-in purity system by the mean-eld theory [1], the Q uantum M onte C arlo [2], and the numerical renormalization group [3, 4]. In this paper we derive the ground state and the free energy in the same level of approximation as is used for the  $f^2$  lattice system. Then by comparing the electronic state of the  $f^2$  lattice periodicity.

In ref. [1] the two-im purity Anderson model was solved by the mean-eld theory. It was shown that the intersite hybridization gives smooth change from the limit of two independent K ondo states (K ondo pair) to the pair singlet state as the intersite interaction increases. Physically we expect the same situation even though the occupation of f electrons at each site is very close to unity. The limiting case is described by the two-im purity K ondo model. A lthough the Anderson lattice model is more general than the K ondo lattice model, the CEF state is harder to treat in the mean-eld theory. Since we have adopted the K ondo lattice model with  $f^2$  congurations, we need to solve the two-impurity K ondo model for comparison.

The two-im purity model is given by

$$H_{2imp} = \begin{array}{c} X \\ H_{2imp} \\ k \end{array} = \begin{array}{c} X \\ R_{k} c_{k}^{y} c_{k} + J \\ R_{j} = 1 \end{array} \\ S_{j}^{f} S_{j}^{f} + \frac{1}{4} n_{j}^{f} n_{j}^{c} \\ + I S_{1}^{f} S_{j}^{f} + \frac{1}{4} n_{1}^{f} n_{2}^{f} ; \end{array}$$
(11)

where J; I > 0 and j (= 1; 2) labels sites of f electrons. There is only a single conduction band since even in this case di erent screening channels are present around each in purity. We take the mean-elds in the form analogous to the  $f^2$  lattice system : 0 ne is given by

$$V_{j} = \frac{J}{2} \sum_{k}^{X} e^{ik \cdot r_{j}} h f_{j}^{Y} q_{k} i$$

which represents the ctitious hybridization between f and conduction electrons at each site. The other is given by

$$R = \frac{I}{2}^{X} hf_{1}^{y} f_{2} i$$

which expresses the mixing between two felectrons. As before the Lagrange multiplier terms

are added to eq. (11) to enforce the constraints on the number of felectrons.

There are two dimensionless parameters A; B which represent the intersite hybridization e ect via conduction electrons. Namely we de ne

$$j j^{2} \int_{k}^{X} \frac{e^{ik r}}{i!_{n} ||_{k}} = \left[ \mathbb{B} + iA \operatorname{sgn}(!_{n}) \right] ;$$
(12)

Here, the magnitudes of A and B depend on both the distance r between faites and the band structure of conduction electrons, but they are always less than unity [1]. The parameter A causes asymmetry in the density of states of bonding and antibonding fatates: In the case R > 0, with A > 0 (< 0) the density of states of the bonding states becomes wider (narrower) than that of the antibonding states. On the other hand the parameter B controls the splitting between bonding and antibonding fatates. The left-hand side of eq. (12) is analogous to the term with in eq. (6) if one interchanges sites in the former with channels in the latter. In the two-impurity system there are three characteristic states: The rst is the K ondo-pair state where the K ondo e ect occurs independently at each site (€ 0; R = 0); the second is the pair-singlet state where the pair-singlet of felectrons is formed without help of conduction electrons (= 0; R € 0); the third is the mixed state which interpolates the above two states (€ 0; R € 0).

# 4 Stability of Itinerant and Localized States

## 4.1 Zero tem perature

We have solved the mean-eld equations numerically at zero temperature both for the  $f^2$  lattice and the two-in purity systems. Table 1 summarizes the parameters used in the calculation. Figure 1(a) shows the ground-state energy per site in the  $f^2$  lattice system at zero temperature. The origin of energy is taken to be that of the Ferm i sea without f electrons. The abscissa represents the bare CEF splitting in units of  $T_K$ . The notations  $E_K$ ,  $E_{CEF}$  and  $E_m$  ix represent the ground-state energies of K ondo, CEF and m ixed states, respectively. The elect of intersite hybridization depends only on its absolute value. Thus results of  $E_m$  ix with = 0 and = 0.4 are shown as representative cases in Fig. 1(a).

We nd that  $E_{m\ ix}$  is larger than  $E_K$  and  $E_{CEF}$  for all combinations of parameters  $I=T_K$  and . Therefore the change from the K ondo state to the CEF state occurs discontinuously at the critical point  $I=T_K=4$ . The mixed state which would have interpolated the K ondo and CEF states smoothly is not stabilized actually; with increasing intersite hybridization, the mixed state with energy  $E_{m\ ix}$  becomes larger in the mean-eld theory. This is seen by the fact that  $E_{m\ ix}$  with =0.4 is larger than that with =0 in Fig. 1(a). The reason is the following: If >0 and R >0, the density of states of the bonding f states has a larger width than that of the antibonding f states. The ground-state energy is given by the sum of single-particle energies of occupied states. Namely, we integrate the total density of states multiplied by w from 1 to 0. Since the integral without w is xed by the number conservation, the total energy increases by the asymmetry induced by . Sim ilarly in the case of <0 and R >0, the asymmetry of the density of states in the opposite direction increases the energy again.

For com parison, Fig.1 (b) shows the ground-state energy of felectrons in the two-impurity system at zero tem perature. We have tried various values of A and con meed that A does not in uence the relative stability of the phases. On the contrary the value of B drastically a ects the ground state. Hence, we x A = 0.2 and vary B as a free parameter. We note that if B = 0,  $E_{m ix}$  is larger than both  $E_{K}$  and  $E_{pair}$  for any value of  $I=T_{K}$ . This situation is analogous to that in the  $f^{2}$  lattice system. As a result an abrupt change from the K ondo-pair state to the pair-singlet state occurs as  $I=T_{K}$  is increased. At the critical point of  $I=T_{K} = 2.5$ , the two kinds of singlet states are degenerate. Thus one observes the divergence of physical quantities such as the susceptibility and the speci c heat coe cient. We have checked that this level-crossing behavior remains the same as long as  $\beta j < 1 = .0$  n the contrary, if the hybridization e ect is large ( $1 = \langle \beta j < 1 \rangle$ , the K ondo-pair state connects continuously with the pair-singlet state

through the mixed state. In this case no divergence occurs. This is shown in Fig.1 (b) by the result that  $E_{m ix}$  (B = 0:4) is lower than both  $E_K$  and  $E_{pair}$  for any value of I=T<sub>K</sub>. These results obtained in the m ean-eld approximation agree with those in refs. [2, 4, 1] for the two-impurity Anderson m odel.

W e note that A controls asymmetry of the density of states of felectrons with respect to the Fermi level, just as does in the  $f^2$  lattice system . We have con m ed that  $E_{m ix}$  becomes larger as  $\lambda$  jincreases with B being xed. Thus the parameter A plays the same role as in the f lattice system. However in the lattice system we do not have the parameter corresponding to B in the impurity system. Hence there is no stable mixed state in the f<sup>2</sup> lattice system in our calculation. M athem atically the ine ectiveness in stabilizing the mixed state comes from the absence of k-summation in the self-energy of the  $f^2$  lattice system .

#### 4.2 Finite Tem perature

The mean-eld equations are solved num erically also at nite tem peratures, and the free energies are derived. Figure 2 (a) shows tem perature dependence of free energies per site for three di erent states in the f<sup>2</sup> lattice system : K ondo, CEF and m ixed states. Even though the CEF singlet is the ground state, there is a case where the itinerant state is realized at higher tem peratures. We did that the free energy of the mixed state is larger than those of the other two states for all values of parameters  $I{=}T_{\rm K}$  and ~ . Therefore, the transition between the K ondo and CEF phases occurs as a st-order one.

Figure 2(b) shows free energies in the two-in purity system . The notations  $F_{K}$ ,  $F_{pair}$  and  $F_{mix}$ represent the free energies of the K ondo-pair, pair-singlet and m ixed states, respectively. It is seen that with B = 0,  $F_{m ix}$  is larger than  $F_{K}$  and  $F_{pair}$ . As in the case of zero tem perature, the m ixed state is not stabilized as long as  $\beta j < 0.08$  for all values of  $I=T_K$ . On the other hand,  $F_{m ix}$  with B = 0.4 in Fig. 2(b) is lower than both  $F_K$  and  $F_{CEF}$ . We have checked that with  $0.08 < \beta j < 1$  the mixed state is stabilized at all tem peratures.

From these results we infer that the parameter B in the two-in purity system plays a decisive role also at nite tem peratures. Furtherm ore in the  $f^2$  lattice system there is no tem perature region where the mixed state is stabilized. In other words, the hybridization e ect which m ediates between K ondo and CEF phases is ine ective, and the transition occurs discontinuously.

#### D iscussions 5

#### Comparison with two-impurity systems 5.1

In considering the relevance of the mean-eld theory, we is take the case of impurity systemis. The physical di erence between the two-impurity K ondo and Anderson m odels is whether there is charge uctuations of felectrons or not. Reliable know ledge is available for both models from several num erical

calculations. Computation using the num erical renorm alization group derived a level crossing between the K ondo-pair state and the pair-singlet state  $\beta$ ]. As a result divergence of the staggered susceptibility occurs at zero tem perature. On the contrary, a quantum M onte C arbo calculation for the two-im purity Anderson model [2] found continuous behavior in physical quantities. This apparent con ict was resolved by Sakai et al. [4] who identi ed the origin of the continuous crossover as the bonding-antibonding splitting of forbitals. In the K ondo m odel, the splitting is absent because there is no charge degrees of freedom for felectrons. Thus the divergent behavior is purely a form al consequence of the model since there should always be some amount of charge uctuations in real systems.

For our purpose of studying a new type of phase transition, we regard our model given by eq.(1) only as a simpli ed form of Anderson-type models which are more di cult to analyze by the mean-eld theory. Then the nite order parameters for various phases are rather to be regarded as properties of a corresponding Anderson-type model. In formally exact treatment of eq.(1), all of our order parameters would vanish identically in contrast with the results of the mean- eld theory. However by the same reason as explained above for the two-impurity models, we would rather accept the results of the meaneld theory as a physically possible consequence for more realistic models.

# 5.2 C om parison with the $f^1$ lattice system

It is instructive to take the limits I ! 0 and ! 0 in eq.(1). Then the system becomes equivalent to two independent K ondo lattices. In the half-led case the ground state is either the K ondo insulator or a magnetically ordered phase. The latter state is due to the RKKY interaction which is not taken into account by the mean- eld theory. We note that the ordered state can be either metallic or insulating depending on the magnetic structure. If it is ferrom agnetic, the half-led conduction band leads to the metallic state. As one increases J from zero, the ground state should change from the magnetically ordered state to the insulating one. Subsequently the nature of f electrons changes from the localized character to the itinerant one. Since the entropy is di erent in the two phases, a phase transition can occur from one phase to the other as a function of tem perature.

Let us com pare this phase transition with another one which is known as an artifact of the mean-eld theory. Namely, as tem perature increases in the mean-eld theory, the order parameter of the K ondo insulating phase decreases continuously to zero around the tem perature T  $T_K$ . In the exact theory the local gauge uctuation washes away the transition completely. We emphasize that the possible transition between the K ondo insulator and the magnetically ordered phase should survive the uctuation elect.

Now we consider the case of nite I and . In the mean-eld theory, the K ondo insulating phase does not feel the elect of I and . The resultant state is the same as the direct product of the two f lattices. Hence the second-order transition around T  $T_K$  is again ctitious. One can ask at zero temperature how the magnetic state changes as I increases continuously from 0. For small I, we have the ordered induced moment which arises by mixing of the singlet and triplet levels. At certain critical value of I, the CEF singlet will become more stable than the induced moment. The situation is analogous to the spin chain problem where exchange interactions of alternating strength form dimers with an excitation gap. We note that the felectrons are always localized for any value of I. Thus the change to the K ondo insulator can occur as a phase transition, although both states are spin singlets.

## 5.3 E ects of charge uctuation on the phase transition

In actual  $f^2$  lattice systems there should always be charge uctuation as discussed above. Then any exact eigenstate has some amount of hybridization between f and conduction electrons. However, there can still be two dimenstations of hybridized states: The mst one can be reached by perturbation theory with respect to hybridization. This state is connected with the localized  $f^2$  state. The other state is the itinerant state which is not accessible by such perturbation theory. The latter state instead is simply described by the band picture of felectrons. Thus possibility of the phase transition remains even though e ects of charge uctuations are included.

We note that the transition to the CEF singlet phase is of rst order. A rst-order transition should be less sensitive to uctuation e ects than a second-order one. We plan to check the robustness of the phase transition by using theories [5, 6, 7] m ore reliable than the mean-eld theory.

## 5.4 Possible experimental relevance

W ith respect to experimental relevance, we have to consider also the case where the number of conduction electrons deviates from  $2N_s$ . In the Anderson lattice model with dominant  $f^2$  congurations, the itinerant state then has a nite density of states of felectrons at the Fermi level, and hence is metallic. In this case the Fermi level is shifted from the center of the hybridization gap, and the average occupation of felectrons per site also deviates from 2. Thus in reality the transition from the itinerant state to the localized one is not always an insulator metal transition.

Concerning possible relevance of our theory, we mention two uranium compounds: UN iSn and  $URu_2Si_2$ . In the former case, the insulating state at high temperatures changes via a rst-order transition into a metallic state at T = 43 K. In contrast to our model, however, the metallic state shows the antiferrom agnetic order [8]. As long as the localized picture applies to the low-temperature phase, the driving force of the transition m ay be similar to the one discussed in this paper. It is necessary to include the induced m om ent form ore detailed analysis of UN iSn. In the latter case of UR  $u_2Si_2$ , the CEF singlet model accounts for gross features of highly anisotropic susceptibility and metam agnetic transition [9]. The high-tem perature phase is metallic showing the K ondo e ect in the resistivity. A clear anom aly

in the speci c heat is observed at tem perature  $T_0 = 17.5$  K [10], and the resistivity shows the m etallic behavior also below  $T_0$ . By neutron scattering [11] the antiferrom agnetically ordered m agnetic m om ents were observed below  $T_0$ . The m agnitude of the m om ent is only  $0.04_B$  which is smaller by two orders of m agnitude than the usual m agnitude observed in sim ilar com pounds  $UT_2Si_2$  (T = Pd;Rh). M oreover, the grow th of m om ents with decreasing tem perature does not follow the mean- eld behavior. Strangely, the NM R does not probe the internal eld below  $T_0$  [12]. Thus there is a possibility that the apparent antiferrom agnetism is not a true long-range order, but due to very slow uctuation of U m om ents.

In any case the speci c heat jump at  $T_0$  is too large to be accounted for by the tiny m agnetic m om ent. Thus, the proper order parameter in this ordered phase remains to be identified [13, 14, 15, 16]. We note that the inelastic neutron scattering [11] probed a feature which looks like a CEF excitation below  $T_0$ . This fact may be a key to identify the order parameter. The phase transition seems to be of second order.

In sum m ary, we have shown that the phase transition from the itinerant state to the CEF singlet state occurs as tem perature decreases in the  $f^2$  lattice system in the frame of the mean-eld theory. Properties of the  $f^2$  lattice system were discussed in comparison with the two-impurity system at zero and nite tem peratures. We suggest that the competition between localized and itinerant states of felectrons is the fundam ental driving force for phase transitions in some uranium compounds such as UN iSn and UR  $u_2 Si_2$ . It remains to see to what extent the uctuation eld beyond the mean-eld theory all ects the phase transition.

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Figure 1: The ground-state energies of (a) the  $f^2$  lattice system, and (b) the two-in purity system. In (a),  $E_K$ ;  $E_{CEF}$  and  $E_{m ix}$  correspond to the K ondo (itinerant), CEF (localized) and m ixed states, respectively, and is a parameter to characterize the strength of intersite hybridization. In (b),  $E_K$ ;  $E_{pair}$  and  $E_{m ix}$ show the energies of K ondo-pair, pair-singlet and m ixed states, respectively. The parameter B ( $\beta$  j 1) characterizes the strength of intersite hybridization e ect. A nother hybridization parameter A is xed to be 0.2 (see text).

Figure 2: Free energies of (a) the  $f^2$  lattice system and (b) the two-in purity system. In (a),  $F_K$ ;  $F_{CEF}$  and  $F_{m ix}$  indicate the K ondo (itinerant), CEF and m ixed states, respectively. In (b),  $F_K$ ;  $F_{pair}$  and  $F_{m ix}$  indicate the K ondo-pair, pair-singlet and m ixed states, respectively. The parameter A is xed to be 0.2 as in Fig.1.

Table 1: Param eters for calculation.

	I		$T_{K}$	D
K] —1 1	10 [K]	0	1 [K]	10 <sup>4</sup> [K]
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